

DESCRIPTION

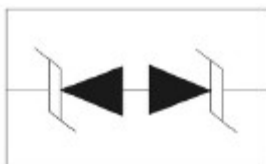
The GESD0301CM is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as VGA, DVI, SDI and other high speed line applications.

This device has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD (electrostatic discharge), and EFT (electrical fast transients).

ORDERING INFORMATION

- ◇ Device: GESD0301CM
- ◇ Package: DFN1006
- ◇ Marking: 3CM
- ◇ Material: Halogen free
- ◇ Packing: Tape & Reel
- ◇ Quantity per reel: 10,000pcs

PIN CONFIGURATION



FEATURES

- ◇ IEC61000-4-2 (ESD) $\pm 15\text{kV}$ (air), $\pm 8\text{kV}$ (contact)
- ◇ IEC61000-4-4 (EFT) 40A (5/50ns)
- ◇ Peak power dissipation: 400W (8/20 μs)
- ◇ Protects one directional I/O line
- ◇ Low clamping voltage
- ◇ Working voltages : 3.3V
- ◇ Low leakage current
- ◇ Low capacitance

MACHANICAL DATA

- ◇ DFN1006 package
- ◇ Terminals: Gold plated, solderable per MIL-STD-750, method 2026
- ◇ Packaging: Tape and Reel
- ◇ Reel size: 7 inch
- ◇ MSL 3

APPLICATIONS

- ◇ Serial and Parallel Ports
- ◇ Notebooks, Desktops, Servers
- ◇ Projection TV
- ◇ Cellular handsets and accessories
- ◇ Portable instrumentation
- ◇ Peripherals

PACKAGE OUTLINE



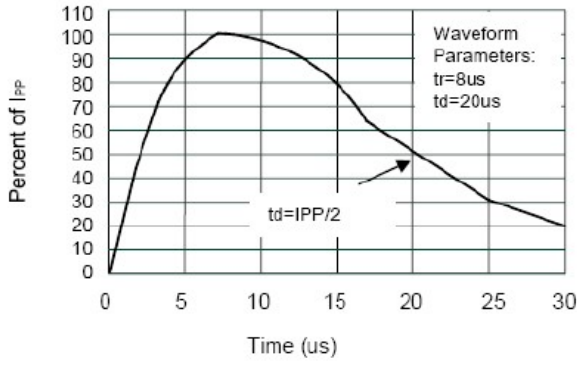
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units
V _{ESD}	ESD per IEC 61000-4-2 (Air)	±30	kV
	ESD per IEC 61000-4-2 (Contact)	±30	
P _{PP}	Peak Pulse Power (8/20μs)	400	W
T _{OPT}	Operating Temperature	-55~150	°C
T _{STG}	Storage Temperature	-55~150	°C

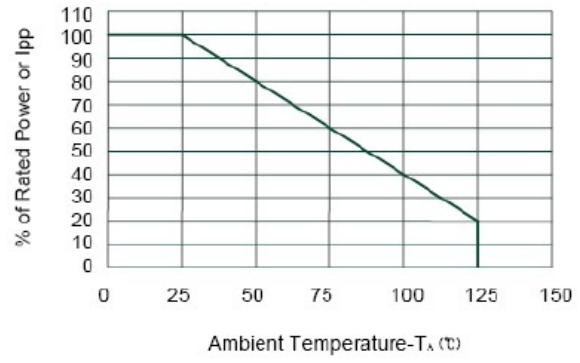
ELECTRICAL CHARACTERISTICS (T_{amb}=25°C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V _{RWM}	Reverse Working Voltage				3.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA	4.0		6.0	V
I _R	Reverse Leakage Current	V _{RWM} = 3.0V			1.0	μA
V _C	Clamping Voltage	I _{PP} = 1A, t _p = 8/20μs			6.5	V
V _C	Clamping Voltage	I _{PP} = 23A, t _p = 8/20μs		13	18	V
C _J	Junction Capacitance	V _R = 0V, f = 1MHz		35	45	pF

ELECTRICAL CHARACTERISTICS CURVE

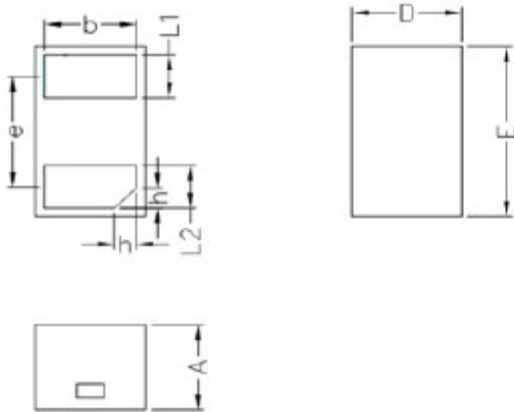


Pulse Waveform



Power Derating Curve

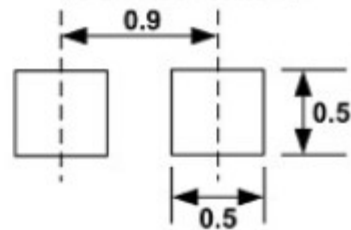
DFN1006 PACKAGE OUTLINE DIMENSIONS



Unit: mm

	MIN	NOM	MAX
D	0.55	0.60	0.65
E	0.95	1.00	1.05
L1	0.20	0.25	0.30
L2	0.20	0.25	0.30
b	0.45	0.50	0.55
e	0.65BSC		
A	0.45	0.50	0.55
h	0.07	0.12	0.17

Dimension: Millimeter
(Stencil thickness: 0.1)



Soldering Footprint